# TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS155C

#### October 1997 - Revised August 2003

### Features

- Buffered Inputs
- Asynchronous Master Reset
- Typical f<sub>MAX</sub> = 60MHz at V<sub>CC</sub> = 5V, C<sub>L</sub> = 15pF, T<sub>A</sub> = 25<sup>o</sup>C
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility, V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility, IJ  $\leq$  1µA at VOL, VOH

# CD54HC164, CD74HC164, CD54HCT164, CD74HCT164

### High-Speed CMOS Logic 8-Bit Serial-In/Parallel-Out Shift Register

### Description

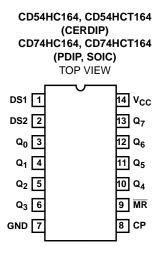
The 'HC164 and 'HCT164 are 8-bit serial-in parallel-out shift registers with asynchronous reset. Data is shifted on the positive edge of Clock (CP). A LOW on the Master Reset ( $\overline{\text{MR}}$ ) pin resets the shift register and all outputs go to the LOW state regardless of the input conditions. Two Serial Data inputs (DS1 and DS2) are provided, either one can be used as a Data Enable control.

### **Ordering Information**

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE
CD54HC164F3A	-55 to 125	14 Ld CERDIP
CD54HCT164F3A	-55 to 125	14 Ld CERDIP
CD74HC164E	-55 to 125	14 Ld PDIP
CD74HC164M	-55 to 125	14 Ld SOIC
CD74HC164MT	-55 to 125	14 Ld SOIC
CD74HC164M96	-55 to 125	14 Ld SOIC
CD74HCT164E	-55 to 125	14 Ld PDIP
CD74HCT164M	-55 to 125	14 Ld SOIC
CD74HCT164MT	-55 to 125	14 Ld SOIC
CD74HCT164M96	-55 to 125	14 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

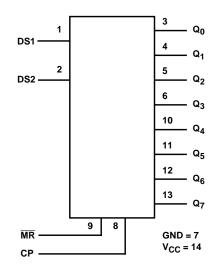
### Pinout



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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### Functional Diagram



#### TRUTH TABLE

		INP	UTS		OUTPUTS			
OPERATING MODE	MR	СР	DS1	DS2	Q <sub>0</sub>	Q <sub>1</sub> - Q <sub>7</sub>		
RESET (CLEAR)	L	Х	Х	Х	L	L-L		
Shift	Н	$\uparrow$	I	I	L	q <sub>0</sub> - q <sub>6</sub>		
	Н	Ŷ	I	h	L	q <sub>0</sub> - q <sub>6</sub>		
	Н	Ŷ	h	I	L	90 - 96		
	Н	Ŷ	h	h	Н	q <sub>0</sub> - q <sub>6</sub>		

H= High Voltage Level.

h= High Voltage Level One Set-up Time Prior To The Low-to-high Clock Transition.

I= Low Voltage Level One Set-up Time Prior To The Low-to-high Clock Transition.

L= Low Voltage Level.

X= Don't Care.

 $\uparrow$ = Transition from Low to High Level.

q<sub>n</sub>= Lower Case Letters Indicate The State Of the Reference Input Clock Transition.

### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub> 0.5V to 7V DC Input Diode Current, I <sub>IK</sub>
For $V_1 < -0.5V$ or $V_1 > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I <sub>OK</sub>
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ±20mA
DC Output Source or Sink Current per Output Pin, IO
For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$
DC V <sub>CC</sub> or Ground Current, I <sub>CC or</sub> I <sub>GND</sub> ±50mA
Operating Conditions

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Temperature Range (T <sub>A</sub> )55 <sup>o</sup> C to 125 <sup>o</sup> C
Supply Voltage Range, V <sub>CC</sub>
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

#### **Thermal Information**

Thermal Resistance (Typical, Note 1)	θ <sub>JA</sub> ( <sup>o</sup> C/W)
E (PDIP) Package	
M (SOIC) Package	86
Maximum Junction Temperature	
Maximum Storage Temperature Range	65 <sup>o</sup> C to 150 <sup>o</sup> C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

### **DC Electrical Specifications**

			ST ITIONS	TIONS		25°C			-40°C TO 85°C		-55°C TO 125°C								
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX								
HC TYPES									-		2	-							
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V							
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V							
				6	4.2	-	-	4.2	-	4.2	-	V							
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V							
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V							
				6	-	-	1.8	-	1.8	-	1.8	V							
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V							
Voltage CMOS Loads		VIL	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V							
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V							
High Level Output											-4	4.5	3.98	-	-	3.84	-	3.7	-
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	V							
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or	0.02	2	-	-	0.1	-	0.1	-	0.1	V							
Voltage CMOS Loads		VIL	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V							
			0.02	6	-	-	0.1	-	0.1	-	0.1	V							
Low Level Output			4	4.5	-	-	0.26	-	0.33	-	0.4	V							
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V							
Input Leakage Current	lı	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μA							
Quiescent Device Current	ICC	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μA							

## CD54HC164, CD74HC164, CD54HCT164, CD74HCT164

DC Electrical Specifications (Continued)

			ST ITIONS		25 <sup>0</sup> C			-40 <sup>0</sup> C TO 85 <sup>0</sup> C		-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I	V <sub>CC</sub> to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

NOTE:

2. For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

### **HCT Input Loading Table**

INPUT	UNIT LOADS
Date Shift-In (1, 2)	0.3
MR	0.9
Clock	0.7

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications table, e.g.  $360\mu A$  max at  $25^{\circ}C$ .

### **Prerequisite For Switching Function**

			25 <sup>o</sup> C		-40 <sup>0</sup> C T	O 85 <sup>0</sup> C	-55 <sup>0</sup> C TO 125 <sup>0</sup> C		
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	
HC TYPES									
Maximum Clock Frequency f <sub>N</sub>	f <sub>MAX</sub>	2	6	-	5	-	4	-	MHz
		4.5	30	-	24	-	20	-	MHz
		6	35	-	28	-	24	-	MHz
MR Pulse Width	t <sub>w</sub>	2	60	-	75	-	90	-	ns
		4.5	12	-	15	-	18	-	ns
		6	10	-	13	-	15	-	ns

## CD54HC164, CD74HC164, CD54HCT164, CD74HCT164

### Prerequisite For Switching Function (Continued)

			25	o <sup>o</sup> C	-40°C 1	ГО 85 <sup>0</sup> С	-55 <sup>0</sup> C T	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
CP Pulse Width	t <sub>W</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Set-up Time	t <sub>SU</sub>	2	60	-	75	-	90	-	ns
		4.5	12	-	15	-	18	-	ns
		6	10	-	13	-	15	-	ns
Hold Time	t <sub>H</sub>	2	4	-	4	-	4	-	ns
		4.5	4	-	4	-	4	-	ns
		6	4	-	4	-	4	-	ns
MR to Clock,	t <sub>REM</sub>	2	80	-	100	-	120	-	ns
Removal Time		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
HCT TYPES				-					-
Maximum Clock Frequency	f <sub>MAX</sub>	4.5	27	-	22	-	18	-	MHz
MR Pulse Width	t <sub>w</sub>	6	18	-	23	-	27	-	ns
CP Pulse Width	t <sub>w</sub>	4.5	18	-	23	-	27	-	ns
Set-up Time	ts∪	6	12	-	15	-	18	-	ns
Hold Time	tн	4.5	4	-	4	-	4	-	ns
MR to Clock, Removal Time	t <sub>REM</sub>	6	16	-	20	-	24	-	ns

Switching Specifications Input t<sub>r</sub>, t<sub>f</sub> = 6ns

		TEST		25 <sup>0</sup> C		-40°C TO 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	TYP	МАХ	МАХ	MAX		
HC TYPES									
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	170	212	255	ns	
CP to Q <sub>n</sub>			4.5	-	34	43	51	ns	
		C <sub>L</sub> = 15pF	5	14	-	-	-	ns	
		C <sub>L</sub> = 50pF	6	-	29	36	43	ns	
MR to Q <sub>n</sub> t <sub>PL</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	140	175	210	ns	
			4.5	-	28	35	42	ns	
		C <sub>L</sub> = 15pF	5	11	-	-	-	ns	
		C <sub>L</sub> = 50pF	6	-	24	30	36	ns	
Output Transition Times	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	75	-	110	ns	
			4.5	-	15	-	22	ns	
			6	-	13	-	19	ns	
Maximum Clock Frequency	f <sub>MAX</sub>	C <sub>L</sub> = 15pF	5	60	-	-	-	MHz	
Input Capacitance	C <sub>IN</sub>	-	-	-	10	10	10	pF	

### CD54HC164, CD74HC164, CD54HCT164, CD74HCT164

		TEST		25 <sup>0</sup> C		-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	TYP	MAX	МАХ	MAX	UNITS
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	47	-	-	-	pF
HCT TYPES								
Propagation Delay, CP to Q <sub>n</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	36	45	54	ns
		C <sub>L</sub> = 15pF	5	15	-	-	-	ns
MR to Q <sub>n</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	38	46	57	ns
		C <sub>L</sub> = 15pF	5	16	-	-	-	ns
Output Transition Times	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	15	19	22	ns
Input Capacitance	C <sub>IN</sub>	-	-	-	-	-	-	pF
Maximum Clock Frequency	f <sub>MAX</sub>	C <sub>L</sub> = 15pF	-	54	-	-	-	MHz
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	49	10	10	10	pF

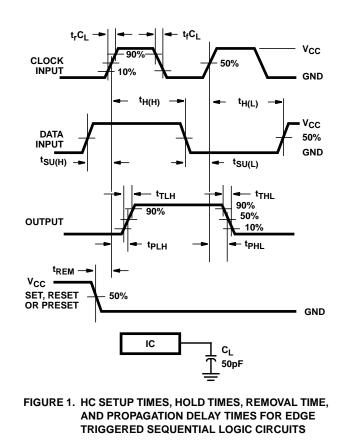
Switching Specifications Input  $t_r$ ,  $t_f = 6ns$  (Continued)

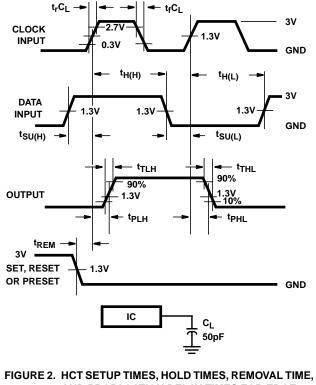
NOTES:

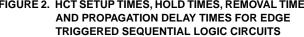
3.  $C_{PD}$  is used to determine the dynamic power consumption, per device.

4.  $P_D = V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 + f_O)$  where  $f_i$  = Input Frequency,  $f_O$  = Output Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

### **Test Circuits and Waveforms**









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### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
5962-8970401CA	ACTIVE	CDIP	J	14	1	TBD	Call TI	Call TI	
CD54HC164F	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	
CD54HC164F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	
CD54HCT164F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	
CD74HC164E	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HC164EE4	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HC164M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC164M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC164M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC164M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC164ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC164MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC164MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC164MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC164MTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT164E	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HCT164EE4	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HCT164M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT164M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT164M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
CD74HCT164M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT164ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT164MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT164MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT164MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT164MTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and pa

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## PACKAGE OPTION ADDENDUM



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#### OTHER QUALIFIED VERSIONS OF CD54HC164, CD54HCT164, CD74HC164, CD74HC164 :

• Catalog: CD74HC164, CD74HCT164

• Military: CD54HC164, CD54HCT164

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

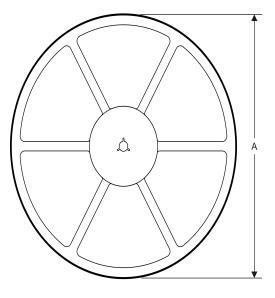
# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION

#### REEL DIMENSIONS

Texas Instruments





TAPE AND REEL INFORMATION

#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

All dimensions are nominal	1											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC164M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC164MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT164M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT164MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC164M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HC164MT	SOIC	D	14	250	367.0	367.0	38.0
CD74HCT164M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HCT164MT	SOIC	D	14	250	367.0	367.0	38.0

J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

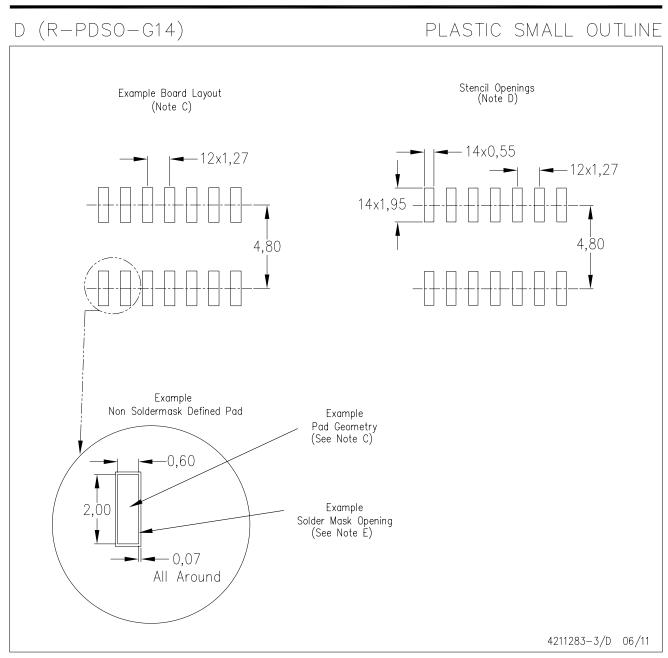
PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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